

UNITED STATES PATENT AND TRADEMARK OFFICE  
**CERTIFICATE OF CORRECTION**

PATENT NO. : 6,548,912 B1  
DATED : April 15, 2003  
INVENTOR(S) : Graff et al.

Page 1 of 1

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

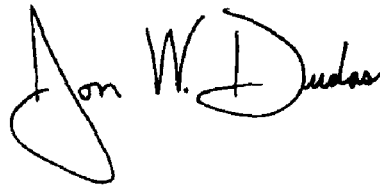
Column 14,

Line 35, add the following claims:

57. The encapsulated microelectronic device of claim 46 wherein the two barrier layers are made of different barrier materials.
58. The encapsulated microelectronic device of claim 1 wherein the oxygen transmission rate through the at least one first barrier stack is less than 0.005 cc/m<sup>2</sup>/day at 38°C and 90% relative humidity.
59. The encapsulated microelectronic device of claim 1 further comprising an overcoat layer adjacent to the at least one first barrier stack on a side opposite the microelectronic device.
60. The encapsulated microelectronic device of claim 1 wherein the overcoat layer is selected from organic layers, inorganic layers, planarizing layers, transparent conductors, antireflective coatings, or combinations thereof.

Signed and Sealed this

Tenth Day of August, 2004

A handwritten signature in black ink, reading "Jon W. Dudas". The signature is stylized, with a large, looped initial "J" and a distinct "D".

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JON W. DUDAS  
*Acting Director of the United States Patent and Trademark Office*